PERFORMANCE SPECIFICATION

Semiconductor Device, Field Effect Radiation Hardened (Total Dose and Single Event Effects) Transistor, N-Channel Silicon, Type 2N7410, JANSD and JANSR

MIL-PRF-19500/638B, dated 07 May 2004, has been reviewed and determined to be valid for use in acquisition.

Custodians:  Preparing Activity:
Army - CR  DLA - CC
Navy - EC
Air Force - 85
DLA - CC
Other - NA

NOTE: The activities above were interested in this document as of the date of this document. Since organizations and responsibilities can change, you should verify the currency of the information above using the ASSIST Online database at https://assist.daps.dla.mil.